



APPLICATIONS

Wireless Network
Telecom/Datacom
Industry Control System
Distributed Power Architectures
Semiconductor Equipment
Microprocessor Power Applications

FEATURES

- OUTPUT CURRENT UP TO 6A
- SMALL SIZE AND LOW PROFILE :
0.80" X 0.45" X 0.25" (SMD) ; 0.90" X 0.40" X 0.24" (SIP)
- HIGH EFFICIENCY - 89% @ 3.3V FULL LOAD
- INPUT RANGE FROM 8.3VDC TO 14.0VDC
- FIXED SWITCHING FREQUENCY (300KHZ)
- SMD & SIP PACKAGES
- OUTPUT VOLTAGE PROGRAMMABLE FROM 0.75VDC TO 5.0VDC
VIA EXTERNAL RESISTOR
- INPUT UNDER-VOLTAGE LOCKOUT
- UL60950-1, EN60950-1 AND IEC60950-1 LICENSED
- ISO9001 CERTIFIED MANUFACTURING FACILITIES
- COMPLIANT TO RoHS EU DIRECTIVE 2002/95/EC

OPTIONS

Positive Logic Remote on/off

DESCRIPTION

DOS06-12T (SMD type), DOH06-12T (for Vertical Mounting SIP type) and DOH06-12TA (for Horizontal Mounting SIP type) are non-isolated DC/DC converters that can deliver up to 6A of output current with full load efficiency of 89% at 3.3V output.

TECHNICAL SPECIFICATION All specifications are typical at nominal input, full load and 25°C otherwise noted

OUTPUT SPECIFICATIONS			
Output current			6A max
Voltage accuracy	Full load and Vin(nom)		± 2%Vo(set)
Minimum load			0%
Line regulation	Vin=Vin(min) to Vin(max) at Full Load		± 0.3%Vo(set),typ
Load regulation	No Load to Full Load		± 0.4%Vo(set),typ
Ripple and noise (Note2)	20MHz bandwidth		20mVrms,max 50mVp-p,max
Temperature coefficient			±0.4%, typ
Dynamic load response (Note 2)	ΔIo / Δt = 2.5A/μS, Vin(nom)	Peak deviation	200mV,typ
	Load change step (50% to 100% or 100% to 50% of Io(max))	Setting time (Vo<10%peak deviation)	25μS,typ
Dynamic load response (Note 3)	ΔIo / Δt = 2.5A/μS, Vin(nom)	Peak deviation	50mV,typ
	Load change step (50% to 100% or 100% to 50% of Io(max))	Setting time (Vo<10%peak deviation)	50μS,typ
Output current limit			200%,typ
Output short-circuit current		Hiccup, automatics recovery	
External load capacitance	ESR ≤ 1mΩ		1000μF,max
	ESR ≥ 10mΩ		3000μF,max
Output voltage overshoot-startup	Vin=Vin(min) to Vin(max); F.L.		1%Vo(set)
Voltage adjustability (see fig.1)	(Note 4)		0.7525V ~ 5.0V
GENERAL SPECIFICATIONS			
Efficiency			See table
Isolation voltage			None
Switching frequency			300KHz, typ
Approvals and standard			IEC60950-1, UL60950-1, EN60950-1
Dimensions	SMD		0.80 X 0.45 X 0.25 Inch (20.3 X 11.4 X 6.5 mm)
	SIP		0.90 X 0.40 X 0.24 Inch (22.9 X 10.2 X 6.0 mm)
Weight			2.8g(0.1oz)
MTBF (Note 1)	BELLCORE TR-NWT-000332		1.990 x 10 ⁷ hrs
	MIL-HDBK-217F		3.007 x 10 ⁶ hrs

INPUT SPECIFICATIONS			
Input voltage range	Vo(set) ≤ 3.63V	Vin(nom) = 12V	8.3 – 14VDC
	Vo(set) > 3.63V		8.3 – 13.2VDC
Maximum input current	Vin=Vin(min); Io=Io(max)		4.5A
Input filter (Note 5)			C filter
Input no load current (Vin=12V, Io=0, module enabled)	Vo(set) = 0.75Vdc		17mA,typ
	Vo(set) = 5.0Vdc		100mA,typ
Input under voltage lockout	Start-up voltage		7.9V,typ
	Shutdown voltage		7.8V,typ
Input reflected ripple current	5~20MHz, 1μH source impedance		30mA-p-p
ENVIRONMENTAL SPECIFICATIONS			
Operating ambient temperature			-40°C ~ +85°C(with derating)
Storage temperature range			-55°C ~ +125°C
Thermal shock			MIL-STD-810F
Over temperature protection			140°C,typ
FEATURE SPECIFICATIONS			
Remote ON/OFF(Note 6)			
Negative logic(standard)	ON = 0V < Vr < 0.3V		IIN=10μA,max
	OFF = 2.5V < Vr < Vin(max)		IIN=1mA,max
Positive logic(option)	ON = (Vin-4) < Vr < Vin(max)		IIN=10μA,max
	OFF=0V < Vr < 0.3V		IIN=1mA,max
Input current of Remote control pin			10μA~1.0mA
Remote off state input current	Nominal Vin		1.2mA,typ
Rise time	Time for Vo to rise from 10% to 90%of Vo(set)		6ms,max.
Turn-on delay time	Case 1 (Note 7)		3ms,typ
	Case 2 (Note 8)		3ms,typ





Model Name	ON/OFF Logic	Package	Input Voltage	Output Voltage	Output Current		Efficiency (%) 12Vin, 3.3Vdc@6A
					Min. Load	Max. Load	
DOS06-12T	Negative	SMD	Vo(set) ≤ 3.63V Vin = 8.3-14Vdc	0.75 ~ 5.0Vdc	0A	6A	89%
DOS06-12T-P	Positive						
DOH06-12T	Negative	Vertical Mounting SIP	Vo(set) > 3.63V Vin = 8.3-13.2Vdc				
DOH06-12T-P	Positive						
DOH06-12TA	Negative	Horizontal Mounting SIP					
DOH06-12TA-P	Positive						

Note

- BELLCORE TR-NWT-000332. Case 1: 50% Stress, Temperature at 40°C.
MIL-HDBK-217F Notice2 @Ta=25 °C, Full load(Ground, Benign, controlled environment).
- External with C_{out} = 1μF ceramic/10μF tantalum capacitors.
- External with C_{out} = 2x150μF polymer capacitors.
- Output voltage programmable from 0.7525V to 5V by connecting a single resistor (shown as R_{trim} in Table 1) between the TRIM and GND pins of the module. To calculate the value of the resistor **R_{trim}** for a particular output voltage **Vo**, use the following equation:

$$R_{trim} = \left[\frac{10500}{V_o - 0.7525} - 1000 \right] \Omega$$

- It's necessary to equip the external input capacitors at the input of the module. The capacitors should connect as close as possible to the input terminals that ensuring module stability. The external C_{in} is 2x47μF ceramic capacitors at least.
- Device code with suffix "-P" – Positive logic(On/Off is open collector/drain logic input; Signal referenced to GND)
Device code with no suffix – Negative logic (On/Off pin is open collector/drain logic input with external pull –up resistor; signal referenced to GND)
- Case 1 :On/Off input is set to logic low (module on) and then input power is applied (delay from instant at which Vin=Vin(min) until Vo=10% of Vo(set))
- Case 2 :Input power is applied for at least one second and then the On/Off input is set to logic low (delay from instant at which Von/off=0.3V until Vo=10% of Vo(set))

CAUTION: This power module is not internally fused. An input line fuse must always be used.

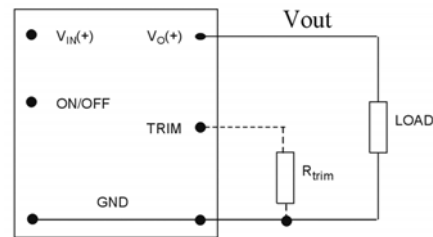
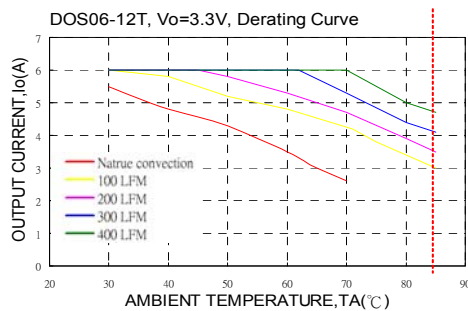


Fig. 1

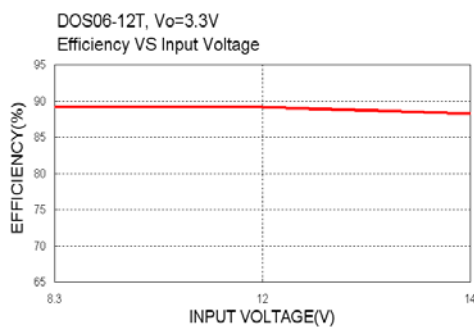
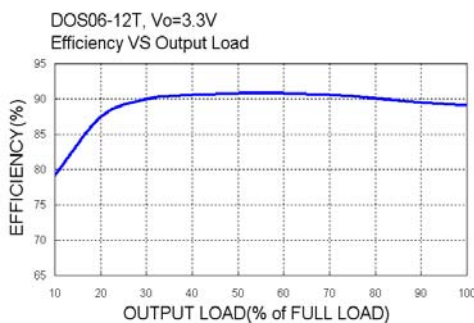


Table 1	
Vo(set) (V)	Rtrim (KΩ)
0.7525	Open
1.2	22.46
1.5	13.05
1.8	9.024
2.5	5.009
3.3	3.122
5	1.472





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